

77. (Twice Amended) The method according to claim 33, wherein the direction in which carriers of said first thin film transistor flow is a direction connecting source and drain regions of said first thin film transistor.

78. (Twice Amended) The method according to claim 36, wherein the direction in which carriers of said first thin film transistor flow is a direction connecting source and drain regions of said first thin film transistor.

79. (Twice Amended) The method according to claim 42, wherein the direction in which carriers of said first thin film transistor flow is a direction connecting source and drain regions of said first thin film transistor.

80. (Twice Amended) The method according to claim 45, wherein the direction in which carriers of said first thin film transistor flow is a direction connecting source and drain regions of said first thin film transistor.

81. (Twice Amended) The method according to claim 47, wherein the direction in which carriers of said first thin film transistor flow is a direction connecting source and drain regions of said first thin film transistor.

Please add new claims 82-84 as follows.

82. (New) The method according to claim 29, wherein the direction in which carriers of said first thin film transistor flow is a direction connecting source and drain regions of said first thin film transistor.

83. (New) The method according to claim 31, wherein the direction in which carriers of said first thin film transistor flow is a direction connecting source and drain regions of said first thin film transistor.